Nucleation and growth of supported clusters at defect sites: Pd/MgO(001)

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Nucleation and growth of Pd on cleaved MgO(001) surfaces were studied by variable-temperature atomic force microscopy in the temperature range 200–800 K. Constant island densities (∼3×10^{12} \text{ cm}^{-2}) were observed over a wide temperature range, indicating nucleation kinetics governed by point defects with a high trapping energy. These results are compared to a rate equation model that describes the principal atomistic nucleation and growth processes, including nucleation at attractive point defects. Energies for defect trapping, adsorption, surface diffusion, and pair binding are deduced, and compared with recent ab initio calculations.

Metal aggregates supported on oxide surfaces have many practical applications due to their catalytic, magnetic, and electrical properties. Consequently, fundamental studies have been carried out on a range of model systems. Although the main microscopic steps governing nucleation and growth of the films are now understood, detailed characterization of these processes has proven difficult. In particular, little is known about the interaction between defects and adsorbed metal atoms. Early transmission electron microscopy studies of metal aggregates supported on oxide surfaces, similar to most metal/oxide systems, as the surface energies are usually higher for metals than for oxides. We demonstrate that the nucleation kinetics in a large temperature range is determined by attractive point defects. With the help of a simple rate equation model we deduce the relevant interaction energies for the Pd/MgO(001) system. It is expected that the understanding of nucleation at defects can be exploited to produce novel nanostructures.

The experiments were performed with a variable-temperature atomic force microscope, mounted in a standard UHV chamber. The AFM, of the Besocke Beetle type, utilizes piezoresistive cantilevers for force detection. This setup allows easy tip exchange without breaking vacuum, and imaging of the MgO samples in the temperature range 100–500 K in contact and noncontact modes. Magnesium oxide disks 2.7 mm thick and 23 mm in diameter were prepared by cleaving a single-crystal rod along the (001) plane under Ar gas and introduced into UHV by a load-lock without exposing them to ambient atmosphere. Heating and cooling were achieved by thermal contact to the sample holder, which could be electron-beam heated and liquid-nitrogen or helium cooled. The sample temperature was calibrated by a 0.1 mm NiCr-Ni thermocouple pair glued to the center of a MgO sample before the experiments. Prior to deposition of Pd the crystal was heated in oxygen (10^{-4} \text{ mbar}, 750 K, 30 min).

 Atomic force microscopy imaging of the surface revealed flat terraces 30–500 nm wide and typically several μm long, separated by mono- or multilayer steps. Palladium was deposited from an electron-beam-heated Pd rod evaporator (0.9 kV electrons, Omicron EFM-4) in a position vertical to the sample surface, with a voltage (+1.25 kV) applied to an aperture between rod and sample to avoid ions reaching the surface. In prior cryotemperature Pd deposition experiments on Pd(110), the flux was calibrated against the ion current by counting the deposited atoms with a low-temperature STM. For the experiments presented here, a coverage of about 0.1 monolayer (ML) was deposited at a rate of 3.2
figure 1. Arrhenius representation of Pd island density \( n_i \) (cm\(^{-2}\)) at 0.1 ML coverage. The solid line is a “best fit” obtained with a rate equation model for \( E_d = 0.2 \), \( E_t = 1.5 \), \( E_b = 1.2 \), and \( E_d = 1.2 \) eV. Insets: noncontact AFM images of Pd deposits on Ar-cleaved MgO(001). The substrate temperature during deposition was 500 and 745 K for these two images. Three arrows point along steps in the 500 K micrograph. The size is 100 \( \times \) 100 nm\(^2\) for both images.

\( \times 10^{-2} \) ML/min (1 ML = \( 1.13 \times 10^{15} \) cm\(^{-2}\)). Auger electron spectra (AES) recorded after deposition revealed no change in sticking of Pd between 200 and 750 K, indicating complete condensation in that temperature range. On the other hand, condensation was clearly incomplete at 800 K. With a nominal exposure to 0.1 ML Pd no islands were seen by AFM and about ten times more Pd had to be evaporated onto the sample to get a similar Pd AES signal.

The influence of the deposition parameters, substrate temperature and flux, has been studied in detail. Atomic force microscopy images were obtained in situ after Pd deposition (see the insets in Fig. 1). We chose to image the particles in the noncontact mode, since in contact mode (forces down to 10 nN) the small Pd particles were displaced by the tip to the borders of the scanned region. For each experiment, Pd was evaporated at a different substrate temperature onto a freshly cleaved MgO surface. For deposition temperatures above 300 K the sample was quenched to room temperature before imaging. Below 300 K, on the other hand, the AFM images were recorded at the deposition temperature to avoid changes in the island density. Since the AFM images represent a convolution of the island shape with the AFM tip, even for the low coverage deposited (0.1 ML) the surface seems largely covered at the lower temperatures.

The island density has been determined from AFM micrographs for a wide range of substrate temperature \( T \) and deposition flux \( F \). The curve in Fig. 1 shows an Arrhenius representation of the island density \( n_i \). The density stays constant over a remarkably wide span of deposition temperature, characteristic of nucleation at defects. The island density of the plateau is the number density of defects that act as traps for Pd (\( \approx 3 \times 10^{12} \) cm\(^{-2}\)). We are not able to identify the nature of these defects unambiguously for the moment, but the majority of the islands are not at steps, which can be readily observed by AFM. These additionally act as nucleation centers, as is seen for the three steps in the 500 K inset in Fig. 1 (arrows). The typical island depletion zone around the steps is apparent in this image. But most of the islands are situated between the steps on the terrace. Our preparation technique of cleaving under Ar clearly results in a reproducible density of such defects. Measurements performed by us with MgO samples cleaved in situ in UHV gave a similar density. We assign the nucleation sites to point defects, most likely surface vacancies.

The influence of Pd flux \( F \) is as follows. In the plateau region (450 K) the island density was unchanged when the flux was varied over two decades. At high temperatures (745 K) the dependence is very weak. In a double logarithmic plot of \( n_i \) versus \( F \) we find a slope of 0.07, well below the expected values between \( \frac{3}{2} \) and 1 for the case of homogeneous nucleation, depending on the size of the critical nucleus.\(^6\)

There are other examples in the literature where nucleation on surface point defects takes place.\(^7,8,9\) In recent examples plateaus in the island density with temperature were found with Fe and Cd growth on CaF\(_2\) surfaces and Fe growth on UHV-cleaved MgO(001).\(^5\) In the latter work a constant island density of \( 6 \times 10^{12} \) cm\(^{-2}\), very comparable to the value observed in the present study, was found between 200 and 500 K, which suggests the operation of a similar growth mechanism.

Defects can be incorporated into either analytical treatments or simulations, at the cost of at least two additional material parameters, the trap density \( n_t \) and energy \( E_t \). The maximum or saturation nucleation density has been derived\(^8\) by extending the equation for homogeneous nucleation.\(^7\) For nucleation at defects this equation is modified by a factor \( (1 + A_t) \), where \( A_t \) is the ratio of the defect-induced to homogeneous nucleation rate.

Our reasoning can be understood using Fig. 2. Local equilibrium is quickly established between adatoms on terraces (density \( n_1 \)) and at defect sites (\( n_{1t} \)). This yields a Langmuir adsorption isotherm for the occupation of traps, including the effect of clusters nucleated on traps (\( n_{1c} \)) which block further adsorption. In the simplest case, where the traps act only on the first atom that joins them, and local entropic effects are ignored, we have

\[ n_{1t} / (n_i - n_{1c}) = A/(1 + A), \]

where \( A = n_1 \exp(E_t/kT) \). Thus for \( A \gg 1 \), strong trapping, almost all the sites unoccupied by clusters are occupied by adatoms. In this model \( A_t = n_{1t} / n_1 \); using these links between \( A_t, A, n_1 \) and \( n_{1c} \), the critical nucleus size \( i \) and the regime of condensation (complete or incomplete) are determined self-consistently as an output of an iterative calculation for given input values of adsorption, diffusion, and binding energies \( (E_d, E_a, E_b) \) plus \( E_t \).\(^7\) Nucleation on terrace sites is strongly suppressed, due to adatom capture by clusters already nucleated on traps. However, when \( n_{1c} > n_1 \), there is little effect on the overall nucleation density. This model results in the S-shaped curves shown in Fig. 3(a) for the whole temperature range studied, illustrated for \( n_i = 2.65 \times 10^{-3} \) ML, \( E_t = 1.5 \) eV, \( E_b = 1.2 \) eV, and \( E_d \) in the range 0.2–0.4 eV, with an assumed value of the diffusion frequency factor.
There are two possibilities, given that an ad-dimer forms a stable nucleus at least up to $T=600$ K. One possibility is that condensation becomes incomplete at this point, but that ad-dimers remain stable, $i=1$. This would indicate a lower limit to the value of $E_b$, with a moderate value of $E_a$ being the important parameter. The other possibility is the inverse, where the first process to intervene is the transition to $i=3$ [due to the square (001) geometry], so that high-temperature data determine $E_b$, and only at even higher temperatures is the condensation incomplete. This means that the limiting process can become breakup of the cluster (on a trap), rather than removal of the adatom from the trap; $E_b$ is not then itself important, provided it is high enough. As condensation becomes incomplete only around 800 K, the first scenario is clearly ruled out. Figure 3(b) shows that $i=1$ at low temperatures, but that the transition to $i=3$ is responsible for the initial drop-off at high temperatures, followed by incomplete condensation at the requisite temperature to agree with observations.

In the framework of the model this interpretation is unambiguous. If $E_b$ is increased markedly then the transition to $i=3$ is delayed to higher temperatures; $E_a$ then has to be reduced to fit the knee of the curve at 600 K, but now the higher-temperature portion of the curve is much too steep, and incomplete condensation sets in too early. If $E_b$ is reduced below about 1.0 eV the transition to $i=3$ occurs too readily to fit the knee of the curve at 600 K, independent of the values of $E_i$ or $E_a$. This plot is therefore close to our “best fit” added in Fig. 1, indicating that $E_a$ and $E_b$ are $\approx 1.2$ eV for Pd/MgO(001), $E_d<0.3$ eV, and $E_i>1.2$ eV. Our confidence in these values is about 0.2 eV, mainly because only an upper limit for $E_d$ has been determined, and its uncertainty is also reflected in the high-temperature features of the curve as apparent from Fig. 3(a).

There are two types of comparison that can be made with other work, notably with experiments by Henry and co-workers,6 and with ab initio and other cluster calculations.10–15 Recent density-functional and other estimates of $E_a$ gave 0.8–1.0 eV,10 with correction downward toward 0.3 eV.11,12 One-quarter ML Pd was calculated to be bound to the surface by about 1.3 eV/atom,12 encouraging us to believe that $E_a$ is of this order. There are several literature estimates of the binding energy of the diatomic molecule Pd$_2$ in the gas phase, covering a huge range from 0.73 to 1.69 eV. However, empirical work and some recent calculations prefer the lower end of the range, with all calculations below 1.35 eV.13 Given that values on surfaces are almost certainly lower than free-space values, $E_b\approx 1.2$ eV may well be quite reasonable. A rough evaluation of the diffusion barrier for the collective migration of a palladium monolayer on MgO has been given as 0.3 eV.14

Finally, the trapping energy of Pd in a surface oxygen vacancy has been estimated to be as high as 2.55 eV,15 provided the defect is a neutral $F_e$ center, which has two electrons located between the vacancy and the Pd adatom. The nature of trapping defects on MgO(001) is, however, not yet clear. Recent density-functional theory calculations of Pt/MgO(001) have suggested that monovacancies ($F_e$ and $V_e$ centers) are strong traps only for the first Pt atom.16 In this calculation the next Pt adatom does not bond, i.e., the defect-
trapped dimer is unstable. This led to the suggestion that Mg-O divacancies are effective traps in generating stable nuclei. Clearly more theoretical work is needed to identify the nature of the trapping sites for Pd/MgO(001) unambiguously.

The island densities and the values for $E_a$, and in particular for $(E_a - E_d)$, that we have deduced are considerably higher than those deduced from a series of experiments by Henry and co-workers. While we cannot at this stage uniquely identify all the causes of these differences, we note that if one has to invoke a spectrum of defect energies in order to explain a continuous variation of $n_x$, with temperature, then the model contains too many parameters (either explicit or implied) to achieve a unique answer. What is clear from the experiments reported here is that our sample preparation technique produces a high density of one type of defect, presumably a surface vacancy, which has a very high trapping energy for Pd adatoms. Under these circumstances the interpretation is clear, provided one remains within the simplest model that explains the results. It is encouraging that the energies needed within this model are close to those resulting from state-of-the-art cluster calculations.

The present study demonstrates that good understanding of the interaction of metals with oxide surfaces can be obtained by AFM experiments combined with a rate equation analysis. The observed trapping and nucleation of Pd clusters at attractive point defects are interesting from a fundamental point of view, but may also be of interest for producing novel supported nanostructures.

5 Crystal rods obtained from Kristallhandel Kelpin, Germany.